32MHz, 64-Channel Serial to Parallel Converter with Push-Pull Outputs

Features

- ► HVCMOS® technology
- ▶ 5.0V CMS Logic
- ► Output voltage up to +80V
- ► Low power level shifting
- ▶ 32MHz equivalent data rate
- ► Latched data outputs
- ► Foreward and reverse shifting options (DIR pin)
- ▶ Diode to VPP allows efficient power recovery
- Outputs may be hot switched

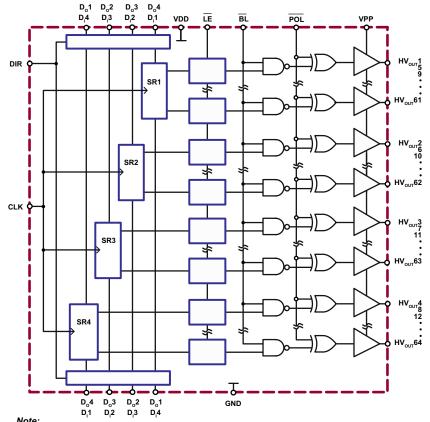
General Description

The HV57708 is a low voltage serial to high voltage parallel converter with push-pull outputs. The device has been designed for use as a driver for EL displays. It can also be used in any application requiring multiple output high voltage

current sourcing and sinking capability such as driving plasma panels, vacuum fluorescent displays, or large matrix LCD displays.

The device has 4 parallel 16-bit registers, permitting data rates 4x the speed of one (they are clocked together). There are also 64 latches and control logic to perform the polarity select and blanking of the outputs. HV_{OUT}1 is connected to the first stage of the first shift register through the polarity and blanking logic. Data is shifted through the shift registers on the logic low to high transition of the clock. The DIR pin causes CCW shifting when connected to GND, and CW shifting when connected to VDD. A data output buffer is provided for cascading devices. This output reflects the current status of the last bit of the shift register (HV_{OUT}64). Operation of the shift register is not affected by the LE (latch enable), BL (blanking), or the POL (polarity) inputs. Transfer of data from the shift registers to the latches occurs when the LE input is high. The data in the latches is stored when the LE is low.

Functional Block Diagram



Each SR (shift register) provides 16 outputs. SR1 supplies every fourth output starting with 1; SR2 supplies every fourth output with 2, etc.

Ordering Information

Part Number	Package Option	Packing
HV57708PG-G	80-Lead PQFP	66/Tray

⁻G denotes a lead (Pb)-free / RoHS compliant package

Absolute Maximum Ratings

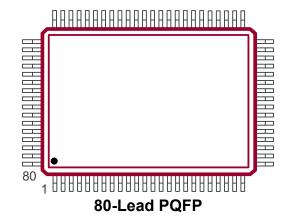
Parameter	Value
Supply voltage, V _{DD}	-0.5V to +7.5V
Output voltage , V _{PP}	-0.5V to +90V
Logic input levels	-0.3V to V _{DD} +0.3V
Ground current ¹	1.5A
Continuous total power dissipation ²	1200mW
Operating temperature range	-40°C to +85°C
Storage temperature range	-65°C to +150°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

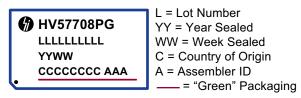
Notes:

- 1. Limited by the total power dissipated in the package.
- 2. For operation above 25°C ambient derate linearly to maximum operating temperature at 20mW/°C.

Pin Configuration



Product Marking



Package may or may not include the following marks: Si or

80-Lead PQFP

Typical Thermal Resistance

Package	$oldsymbol{ heta}_{ja}$
80-Lead PQFP	37°C/W

Recommended Operating Conditions

Sym	Parameter	Min	Max	Units
V _{DD}	Logic supply voltage	4.5	5.5	V
V_{PP}	Output voltage	8.0	80	V
V _{IH}	High-level input voltage	V _{DD} -0.5V	-	V
V _{IL}	Low-level input voltage	0	0.5	V
f _{CLK}	Clock frequency per register	-	8.0	MHz
Τ _Δ	Operating free-air temperature	-40	+85	°C

Notes:

Power-up sequence should be the following:

- 1. Apply ground.
- 2. Apply $V_{\rm DD}$. 3. Set all inputs (D $_{\rm IN}$, CLK, Enable, etc.) to a known state.
- 4. Apply V_{PP}.
- 5. The V_{PP} should not drop below V_{DD} or float during operation.

Power-down sequence should be the reverse of the above.

DC Electrical Characteristics (Over recommended operating conditions unless otherwise noted)

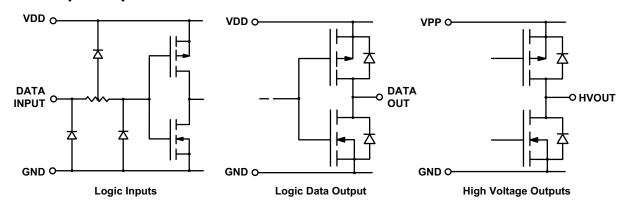
Sym	Parameter		Min	Max	Units	Conditions
I _{DD}	V _{DD} supply current		-	15	mA	$V_{DD} = V_{DD} \text{ max}, f_{CLK} = 8.0 \text{MHz}$
	High voltage supply	current	-	100	μA	Outputs high
l _{PP}	High voltage supply	Surrein	-	100	μA	Outputs low
l _{DDQ}	Quiescent V _{DD} supply	/ current	-	100	μA	$AII V_{IN} = V_{DD}$
\	V _{OH} High level output	HV _{OUT}	65	-	V	$I_{O} = -15 \text{mA}, V_{PP} = +80 \text{V}$
V _{OH}	r light level output	Data out	V _{DD} -0.5	-	V	I _O = -100μA
\/	Low level output	HV _{OUT}	-	7.0	V	$I_{O} = 12mA, V_{PP} = +80V$
V _{OL}	Low level output	Data out	-	0.5	V	I _O = 100μA
I _{IH}	High-level logic input	-	1.0	μA	$V_{IH} = V_{DD}$	
I	Low-level logic input	-	-1.0	μA	V _{IL} = 0V	
V _{oc}	High voltage clamp of	liode	-	1.0	V	I _{oc} = 1.0mA

AC Electrical Characteristics ($T_A = 85^{\circ}\text{C max.}$ Logic signal inputs and Data inputs have t_r , $t_r \leq 5$ ns [10% and 90% points])

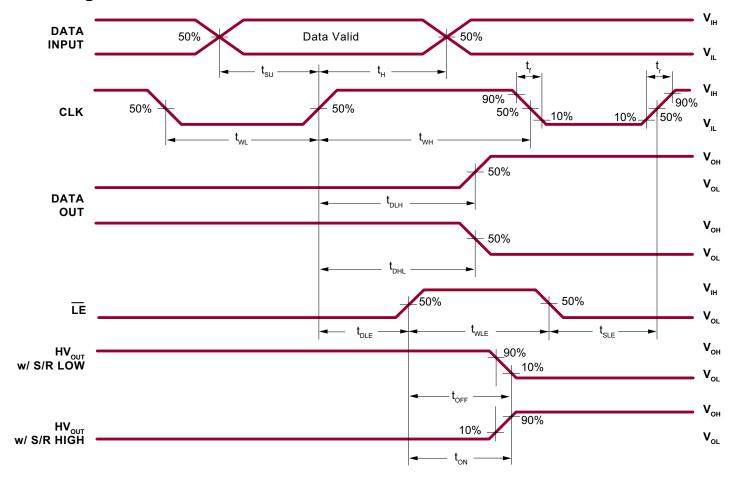
Sym	Parameter	Min	Max	Units	Conditions
f _{CLK}	Clock frequency	-	8.0	MHz	Per register
t _{wL} , t _{wH}	Clock width high or low	62	-	ns	
t _{su}	Data set-up time before clock rises	10	-	ns	
t _H	Data hold time after clock rises	15	-	ns	
t _{on} , t _{off}	Time from latch enable to HV _{OUT}	-	500	ns	C _L = 15pF
t _{DHL}	Delay time clock to data high to low	-	70	ns	C _L = 15pF
t _{DLH}	Delay time clock to data low to high	-	70	ns	C _L = 15pF
t _{DLE} *	Delay time clock to LE low to high	25	-	ns	
t _{wle}	LE pulse width	25	-	ns	
t _{SLE}	LE set-up time before clock rises	0	-	ns	

 $^{^*}t_{\tiny DLE}$ is not required but is recommended to produce stable HV outputs and thus minimize power dissipation and current spikes (allows internal SR output to stabilize).

Input and Output Equivalent Circuits



Switching Waveforms

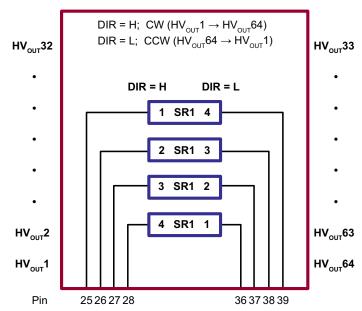


Function Table

			Inpu	ts	Outputs					
Function	Data	CLK	ΪĒ	BL	POL	DIR	Shift Reg	HV Outputs	Data Out	
All O/P high	Х	Х	Х	L	L	Х	-	Н	-	
All O/P low	Х	X	Х	L	Н	Х	-	L	-	
O/P normal	Χ	X	X	Н	Н	X	-	No inversion	-	
O/P inverted	Х	X	Х	Н	L	Х	-	Inversion	-	
Data falls	L		Η	Н	Н	X	L	L	-	
through	Н		Η	Н	Н	X	Н	Н	-	
(latches	L		Н	Н	L	X	L	Н	-	
transparent)	Н		Н	Н	L	X	Н	L	-	
Data stored/	Χ	X	L	Н	Н	X	*	Stored Data	-	
latches loaded	X	X	L	Н	L	x	*	Inversion of stored data		
	D _{I/O} 1-4A _↑		Н	Н	Н	Н	$Q_n \rightarrow Q_{n+1}$	New H or L	D _{I/O} 1-4B	
I/O relation	D _{I/O} 1-4A		L	Н	Н	Н	$Q_n \rightarrow Q_{n+1}$ Previous H or		D _{I/O} 1-4B	
	D _{I/O} 1-4B		L	Н	Н	L	$Q_n \rightarrow Q_{n-1}$	Previous H or L	D _{I/O} 1-4A	
	D _{I/O} 1-4B		Н	Н	Н	L	$Q_n \rightarrow Q_{n-1}$	New H or L	D _{I/O} 1-4A	

Note:

Shift Register Operation



^{* =} dependent on previous stage's state. See Pin configuration for DIN and DOUT pin designation for CW and CCW shift.

Pin Function

Pin #	Function								
1	HV _{ουτ} 24/41								
2	HV _{оυт} 23/42								
3	HV _{оυт} 22/43								
4	HV _{оυт} 21/44								
5	HV _{оυт} 20/45								
6	HV _{ουτ} 19/46								
7	HV _{оυт} 18/47								
8	HV _{оυт} 17/48								
9	HV _{ουτ} 16/49								
10	HV _{ουτ} 15/50								
11	HV _{ουτ} 14/51								
12	HV _{ουτ} 13/52								
13	HV _{оυт} 12/53								
14	HV _{ουτ} 11/54								
15	HV _{ουτ} 10/55								
16	HV _{ουτ} 9/56								
17	HV _{OUT} 8/57								
18	HV _{оит} 7/58								
19	HV _{ουτ} 6/59								
20	HV _{out} 5/60								

Pin #	Function
21	HV _{OUT} 4/61
22	HV _{оит} 3/62
23	HV _{оит} 2/63
24	HV _{OUT} 1/64
25	$D_{IN}1/D_{OUT}4(A)$
26	$D_{IN}2/D_{OUT}3(A)$
27	$D_{IN}3/D_{OUT}2(A)$
28	$D_{IN}4/D_{OUT}1(A)$
29	ĪĒ
30	CLK
31	BL
32	VDD
33	DIR
34	GND
35	POL
36	D _{OUT} 4/D _{IN} 1(B)
37	D _{OUT} 3/D _{IN} 2(B)
38	D _{OUT} 2/D _{IN} 3(B)
39	D _{OUT} 1/D _{IN} 4(B)
40	VPP

Pin #	Function
41	HV _{оυт} 64/1
42	HV _{оυт} 63/2
43	HV _{оυт} 62/3
44	HV _{оυт} 61/4
45	HV _{оυт} 60/5
46	HV _{ουτ} 59/6
47	HV _{оυт} 58/7
48	HV _{оит} 57/8
49	HV _{оυт} 56/9
50	HV _{оит} 55/10
51	HV _{OUT} 54/11
52	HV _{оит} 53/12
53	HV _{оит} 52/13
54	HV _{оит} 51/14
55	HV _{оит} 50/15
56	HV _{оит} 49/16
57	HV _{OUT} 48/17
58	HV _{OUT} 47/18
59	HV _{OUT} 46/19
60	HV _{OUT} 45/20

Pin #	Function
61	HV _{оит} 44/21
62	HV _{оит} 43/22
63	HV _{оит} 42/23
64	HV _{оυт} 41/24
65	HV _{оит} 40/25
66	HV _{оит} 39/26
67	HV _{оит} 38/27
68	HV _{оит} 37/28
69	HV _{оит} 36/29
70	HV _{оит} 35/30
71	HV _{оит} 34/31
72	HV _{оит} 33/32
73	HV _{оит} 32/33
74	HV _{оит} 31/34
75	HV _{оит} 30/35
76	HV _{оит} 29/36
77	HV _{оит} 28/37
78	HV _{оит} 27/38
79	HV _{оит} 26/39
80	HV _{оит} 25/40

Note:

ote:
Pin designation for DIR = H/L.

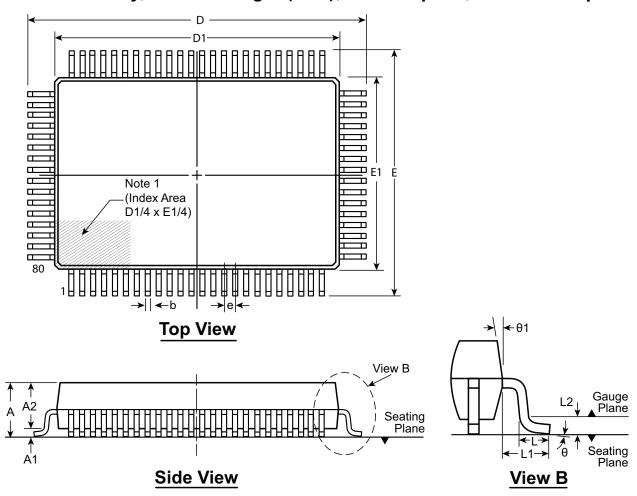
Example: For DIR = H, pin 41 is HV_{OUT}64.

For DIR = L, pin 41 is HV_{OUT}1.

For CW/CCW Shift see function table $Q_N \rightarrow Q_{N+1}$.

80-Lead PQFP Package Outline (PG)

20.00x14.00mm body, 3.40mm height (max), 0.80mm pitch, 3.90mm footprint



Note:

 A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbo	ol	Α	A1	A2	b	D	D1	E	E1	е	L	L1	L2	θ	θ1
Dimen-	MIN	2.80*	0.25	2.55	0.30	23.65*	19.80*	17.65*	13.80*		0.73			0 º	5°
sion	NOM	-	-	2.80	-	23.90	20.00	17.90	14.00	0.80 BSC	0.88	1.95 REF	0.25 BSC	3.5°	-
(mm)	MAX	3.40	0.50*	3.05	0.45	24.15*	20.20*	18.15*	14.20*	200	1.03			7 °	16º

JEDEC Registration MO-112, Variation CB-1, Issue B, Sept. 1995.

Drawings not to scale.

Supertex Doc. #: DSPD-80PQFPPG, Version C041309.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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^{*} This dimension is not specified in the JEDEC drawing.